Temporal Contrast in Ti:Sapphire Lasers: Characterization and Control

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Temporal Contrast in Ti:Sapphire Lasers: Characterization and Control

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Abstract—As ultrafast lasers achieve ever higher focused intensities on target, the problem of ensuring a clean laser-solid interaction becomes more pressing. In this paper, we give concrete examples of the deleterious effects of low-contrast interactions, and address the problem of subpicosecond laser intensity contrast ratio on both characterization and control fronts. We present the new technique of high-dynamic-range plasma-shuttered streak camera contrast measurement, as well as two efficient and relatively inexpensive ways of improving the contrast of short pulse lasers without sacrificing on the output energy: a double-pass Pockels cell (PC), and clean high-energy-pulse seeding of the regenerative amplifier.

Index Terms—Amplified spontaneous emission, chirped-pulse amplification, intensity contrast ratio, pulse cleaning, terawatt lasers.

I. INTRODUCTION

The advent of chirped-pulse amplification (CPA) [1] and subsequent amplification of subpicosecond pulses to higher energies [2]–[5] has brought high-field-science back to university laboratories. Focusing such lasers in gas targets brings high-harmonics generation [6]–[8], electron acceleration [9]–[12], and other interesting physical phenomena such as relativistic self-focusing [13] and high-energy ions from exploding clusters [14]. In solid-target interactions, table-top subpicosecond laser systems have reached focused intensities of more than $10^{20}$ W/cm$^2$ on target, delivered on a timescale much shorter than the hydrodynamical motion of the expanding plasmas. This impulsive energy deposition has made possible ultrafast X-ray sources [15]–[18], high-harmonics generation from solid targets [19] and ion acceleration from plasma bilayers [20].

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II. EFFECT OF PULSE CONTRAST ON SOLID-TARGET INTERACTIONS

For solid-target interactions, the effective laser pulse duration is not the usual full-width at half-maximum (FWHM) of the pulse intensity. Indeed, the only part of the laser pulse that will interact with a solid target is that which precedes and includes the damage threshold fluence. However short the pulse FWHM, if it sits atop a 10-ns pedestal that can create...
a preplasma, its duration might as well be 10 ns. By the time the main pulse hits the target, it will interact with a long scale-length plasma and deposit its energy at relatively low densities, no longer making this a solid-target/subpicosecond-laser experiment. Preplasma formation from the background can occur at intensities ranging from \(10^{8} - 10^{25}\) W/cm\(^2\), depending on the pulse duration (from nanosecond to subpicosecond) [23], [24]. With focused main pulse intensities now routinely in the \(10^{15} - 10^{19}\) W/cm\(^2\) range, an ICR of \(10^{1} - 10^{6}\) is no longer sufficient, as is illustrated by the three following examples.

A. The Generation and Probing of Highly Compressed Solids

Studies of highly compressed solids are particularly relevant to the understanding of dense stars [26], inertial confinement fusion pellet compression [26], [27], and the equation-of-state of high-density materials [28], [29]. In the laboratory, one can use a laser to create a shock wave and compress a target with tens-of-megabars pressures while probing its thermodynamical properties under these extreme conditions with laser-produced X-ray backlight sources [28]–[30] or optical interferometric techniques [31]. When compressing the material with nanosecond pulses, one has to deal with the extra complication of there being significant hydrodynamic motion of the target during the laser pulse [28] unless particular care is taken to properly tamp the shocked material [29]. Using a subpicosecond laser removes this concern by depositing the energy impulsively, in a delta-function-like fashion. One is, therefore, left with the much simpler problem of plasma expansion in the vacuum forming a shock wave in the solid, without further energy input during the measurement [30], [31]. Furthermore, for short-pulse conditions, calculations predict up to gigabar-pressure shock waves lasting picoseconds in duration [32], [33] for high-intensity interactions.

The contrast problem in short-pulse Ti:sapphire lasers restricts them to meaningful solid-target interactions for intensities of \(10^{14}\) W/cm\(^2\) or less [30], [31], making it impossible so far to reach these promised gigabar pressures. For the case of X-ray backlighting shock probing, low contrast impedes two aspects of the experiment: first, the launch of the shock wave and secondly, the generation of the picosecond X-ray source whose duration sets the temporal resolution of the measurement. We observed this in an experiment performed at CUOS which measured the X-ray absorption spectrum of compressed aluminum around the \(L\) photoabsorption edge [30]. The 50-mJ pulses at 780 nm of the CUOS 10-Hz 100-fs laser were split such that 90% of the energy was used to generate a bright broad-band short X-ray source in the 100–200-Å range from a gold target. The other 10% was focused on a 1000-Å film of aluminum. The measurement is a pump-probe acquisition, where the pump is the shock-launching laser pulse and the probe is the X-ray backlighter. The ICR for this experiment was measured to be \(10^{5}\) in the nanosecond timescale with a third-order autocorrelator. The solid-target laser-produced X-ray source duration depends critically on the density at which the laser light is absorbed by the gold target, as it is governed by atomic rates proportional to the electron density in the plasma [18].

![Fig. 1. Shift of the \(L\) photoabsorption edge of a 1000-Å aluminum film as a function of the pump-probe delay. Negative values on the horizontal axis correspond to the X-ray backlight arriving before the laser pulse. A maximum shift of 1.5 Å is observed with pump intensity of \(4 \times 10^{14}\) W/cm\(^2\) (solid line) from a perturbation of the electronic structure in the aluminum as it is compressed by the shock wave launched by the pump laser. A much reduced shift is observed at higher pump intensity (\(2 \times 10^{15}\) W/cm\(^2\), dashed line).](image)

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B. The Production of Energetic Ions

Another field where solid-target interaction is emerging is in the production of fast ions from laser-ablation plumes. Much theoretical work [35]–[38] and relatively less experimental work [39]–[41], [20] has been done on the subject. The theory states that fast electrons accelerated out of the solid target...
Fig. 2. Ion-energy distributions separated by charge state for carbon ablation with 100-fs $10^{15}$ W/cm² laser pulses (C$^{+1}$ peaks at 4211 ions/cm²). The low-energy hump in the distribution can be explained by a hydrodynamic expansion process, and the high-energy part of the distribution by a bilayer ion-accelerated process.

by the ultrashort laser pulse will form a charge separation between the then positively charged target surface and the negatively charged electron cloud in the vacuum. This bilayer will act like a capacitor and set up an electric field that can accelerate the ions from the target to multi-kilo-electron volt or even mega-electron volt energies. This effect only works if both “capacitor plates” are well defined, and thus necessitate a clean laser–solid interaction. Any long-scale-length preplasma would destroy the charge separation before it even begins.

In an experiment performed at CUOS with the 10-Hz 100-fs laser, we detected and analyzed the energy distributions of such energetic ions accelerated from carbon plasmas. The laser pulses at 780 nm were focused to an intensity of $10^{15}$ W/cm² on a solid carbon target with an off-axis parabola, and the ion content of the ablation plume was analyzed with a time-resolved spherical-sector electrostatic ion spectrometer [20]. Ion spectra were collected at the end of the spectrometer on a multichannel plate for a given energy-to-charge ($E/q$) ratio setting of the spectrometer, with the different charge states previously separated in a time-of-flight drift tube. From a series of spectra taken at different $E/q$ settings, one can reconstruct the ion energy distributions, as shown in Fig. 2. The distributions for each charge state show a bimodal shape. The low-energy hump ($E < 1$ keV) has been identified as the thermal part due to hydrodynamic expansion of the plasma, which cannot account for the charge-dependent high-energy hump. The latter is attributed to the plasma bilayer acceleration mechanism, and good agreement for the high-energy peak positions was obtained with a simple capacitor-acceleration model [20].

The effect of varying the contrast of the laser pulse on the production of these energetic ions is shown in Fig. 3. The energy distributions of C$^{+2}$ ions are plotted for a fixed laser intensity of $10^{15}$ W/cm², but for different ICR of the laser; the inset shows the third-order autocorrelation of the two different pulses. In the “high-contrast” case (ICR $\approx 5 \times 10^5$), the energy distribution displays both thermal and accelerated humps, while in the “low-contrast” case (ICR $\approx 2 \times 10^2$) only the thermal part of the distribution remains: the creation of a preplasma by the low-contrast laser pulse has prohibited the formation of the accelerating bilayer. The energetic ions obtained in the high-contrast case are interesting for their relevance to the understanding of various laser absorption mechanisms, fast electron generation and thin-film deposition [42], but also as a potential fast-ion source if scalable to
higher energies. These higher ion energies will come from higher laser intensities on target, which will only be possible with a very good ICR, as the data shown above indicates that a background intensity of $5 \times 10^9$ W/cm$^2$ is enough to dramatically affect fast-ion production.

C. The Development of Laser-Triggered Jitter-Free Detectors

Finally, with the availability of high-repetition-rate short-pulse lasers comes the possibility of averaging multiple laser shots for time-resolved measurements with a high signal-to-noise ratio (SNR). Indeed, recent progress in fast photoconductive switching has made it possible to optically trigger streak cameras with the same laser that is used for the interaction experiment, thereby reducing the shot-to-shot jitter of the camera from tens of picoseconds to subpicosecond values [43]–[47]. Typically, the photoconductive switch is inserted between a power supply and the sweep plates of the camera. The switch has a very high resistivity when not illuminated and it can hold the bias applied by the power supply. When a laser pulse hits the switch (in synchronization with the experimental light hitting the camera’s photocathode), its resistivity goes down and a voltage ramp is seen by the plates of the streak camera, which then sweep the electron beam created by the camera’s photocathode. If the voltage ramp is kept stable on every shot, the jitter on the measurement is reduced appreciably compared to the more classical case where avalanche transistors are used.

The switch system response to laser light is linear at low intensity and saturates at high intensity when the switch resistance becomes comparable to the circuit impedance. The switch is usually operated in the saturation regime to minimize the jitter produced by shot-to-shot variations in laser intensity. However, under these conditions the switch response to the ASE has a contrast ratio to the main pulse response that is lower than the laser intensity contrast ratio. This degradation induces ASE-related jitter in the measurement. Saturable absorbers can be used in front of the switch to reduce this problem [44], but the optimal solution is still to operate with a better laser contrast ratio.

III. MEASURING THE CONTRAST ON THE NANOSECOND SCALE

The four main causes of contrast problems in CPA lasers are: 1) prepulses due to the finite extinction ratio of the polarizing optics and the misalignment of the birefringent materials (nanosecond timescale); 2) shoulders and pedestals arising from spectral clipping and phase distortion in the system (tens of picosecond timescale); 3) a typical ICR of $10^6$ from Kerr-lens mode-locked Ti:sapphire oscillators (for at least several picoseconds) [48], [49]; and 4) considerable ASE from the large amplification ratio in the whole laser (nanosecond timescale). It is, therefore, important to measure the ICR of a laser not only in the vicinity of the subpicosecond pulse, but in the multinanosecond range to have a complete history of the laser pulse. Third-order autocorrelations are well-adapted for high-dynamic-range measurements near the main pulse, but extending them to longer timescales can prohibitively lengthen the procedure time. Streak cameras allow to rapidly measure a signal over a long time duration, but have a dynamic range of about a hundred for a given gain setting, which is far less than the required range of $10^6$–$10^8$. It would therefore be advantageous to find a way to extend the dynamic range of the streak camera such that it can simultaneously record the background and the main pulse. We accomplished this by using two tricks: plasma shuttering to reduce the main pulse intensity, and multishot accumulation to increase the signal of the background and the overall SNR.

A. High-Dynamic-Range Plasma-Shuttered Streak Camera

As mentioned earlier in Section II-C, recent advances in photoconductive switching technology makes possible the use of visible and X-ray streak cameras in near-jitter-free mode. In addition to permit the detection of weak signals through shot accumulation, this technique increases the signal-to-noise ratio by a factor $\sqrt{N}$, where $N$ is the number of shots accumulated, while it conserves the time resolution of the camera. This can de facto increase the dynamic range of the streak camera arbitrarily, provided, as in the case of an ICR measurement for example, that the detector remains unsaturated by the main pulse when the background is detectable. To ensure this, one effectively needs an inverse saturable absorber: a filter that would let through the low-intensity background in front of the pulse but attenuate the main pulse itself.

Laser-induced breakdown in transparent media can provide the necessary shuttering effect [24], [50]–[54]. The low-intensity background in front of the pulse goes through the transparent medium unaffected, while the intense ultrashort laser pulse converts the material into a dense plasma. A high enough laser pulse fluence can lead to the formation of a critical surface in the plasma—where the plasma wave frequency exceeds the laser frequency—making the plasma highly reflective. The transmitted laser energy is then greatly reduced and the plasma shutter can serve as a peak-reduction device to prevent the camera from being saturated or damaged. We demonstrate below that the combination of both photoconductive switching and plasma-shuttering can increase the dynamic range of a visible streak camera to up to $10^9$, and we use this technique to measure the ICR of the 10-Hz 100-fs laser [21].

Fig. 4 shows the experimental setup. We used a picosecond Thomson-CSF TSN-906 visible streak camera modified by
J was focused after the main pulse. For glass lasers, this option.

A small fraction of the 780-nm laser pulse illuminated the photoconductive switch and triggered the sweep of the camera, while 300 μJ was focused in a 150-μm-thick fused silica plate to generate the plasma shutter. The plate was rastered during the experiment to ensure a fresh spot for each shot. The focal spot of the laser on the plate was magnified and imaged onto a 100-μm pinhole in front of the streak camera slit to ensure that the entire aperture area comes from the plasma-shuttered region of the laser-solid interaction.

In Fig. 5, we plot the measured signal normalized to the peak of the laser pulse. The thin vertical line labeled “original pulse” at time zero represents the 100-fs laser pulse used in the experiment. The curves labeled “without plasma shutter” and “with plasma shutter” are the measurements with low input energy (i.e., no breakdown on the sample) and with full input energy (plasma shutter breakdown on the sample), respectively.

The measured temporal width of the main pulse was 25-ps FWHM, due to a combination of space-charge broadening in the streak camera and residual jitter due to the shot-to-shot laser energy fluctuations (±5%). The space-charge broadening was a consequence of operating the camera at a high signal level to enhance its dynamic range, and for the sake of simplifying the experiment we tolerated a similar level of jitter-related broadening which could have been reduced if needed to less than a picosecond with proper use of a saturable absorber in front of the switch. Since the goal of this experiment was to characterize the ASE background of the pulse in the nanosecond timescale, the 25-ps temporal resolution was considered adequate. The measured ICR is about 10⁵, in agreement with a third-order autocorrelation of the laser system in the same configuration (see Section IV-B). The dynamic range of the measurement is given by the lowest signal level measured at 10⁻⁷ after the main pulse. The abrupt drop of signal after the main pulse is evidence that the sample used in the experiment becomes opaque after the plasma density reached the breakdown level during the main pulse. The dynamic range of the technique can be pushed further by optimizing the plasma imaging geometry (using a smaller pinhole) and by replacing the fused silica plate by a material with a lower damage threshold (so the reflective critical plasma density is achieve earlier into the main pulse for less transmitted light). Preliminary experiments with better imaging and a low-damage-threshold photopolymer confirm that the plasma-shuttered streak camera system can reach a dynamic range of 10⁹.

IV. CONTRAST IMPROVEMENT METHODS

Characterizing the ICR is only half the battle, one must also improve it. The figure of 10⁻³–10⁻⁵ given earlier as a typical ICR for glass and Ti:sapphire lasers is representative of most, but a few groups have focused particular attention on improving the ICR of their lasers [55], [56].

Incomplete recompression can always be corrected with proper alignment of the system and various third- and fourth-order compensation tricks [57]–[60], but prepulses and ASE are sometimes more problematic. Frequency doubling takes advantage of the nonlinearity of the doubling process to suppress the low-intensity background, and more-or-less squares the ICR to values better than 10¹⁰. For glass lasers, this option is a viable one because of the relatively long pulse durations (≈450 fs): one can use a thick, efficient doubling crystal without significantly affecting the pulse duration. Conversion efficiencies of up to 80% have been reported in this case [61]. For shorter Ti:sapphire pulses (<100 fs), thick crystals become problematic and doubling efficiencies are usually on the order of 25%, which constitute a serious loss in pulse energy. Saturable absorbers can remove ASE in femtosecond dye amplifiers, but their use in CPA systems could induce spectral shift and narrowing of the highly chirped pulses. Also, the ASE overlapped on the stretched pulse would not be removed, leaving a pedestal with a duration of the stretched pulse. Removing the prepulses and the ASE with saturable absorbers after compression would involve considerable energy losses even in the main pulse and degrade the quality of the pulse through nonlinear propagation in the absorber. From the standpoint of solid-target interactions, brute-force methods to clean the pulse include frequency doubling the recompressed pulse, using saturable absorbers and adding extra Pockels’ cells in the amplification chain [55]. Another way of diminishing the ASE and prepulse problems is to replace the regenerative amplifier by one or several multipass amplifiers [56].

Using a combination of the methods above, it has been reported that one can improve the ICR to values of 10⁸–10⁹ [55], [56]. We present here two complementary ways to
improve the ICR of a laser, without major changes to the original system.

A. Double-Pass, High-Contrast Pockels Cell

The third “brute-force” method listed above to improve the ICR involves PC’s. Many CPA laser systems include PC’s to bring down the repetition rate from the oscillator for the amplification stages or to remove unwanted prepulses generated in regenerative amplifiers. The use of a single PC will typically produce contrasts of at best $5 \times 10^3$ between the switched pulse and the leakage of pulses through the device. In order to produce better contrasts ($10^5$), it is common to place two PC’s in line [55], but this solution can be rather costly. A less expensive alternative to this approach is to use a single PC twice by reflecting the beam back through the cell. Usually, this would require some misalignment of the PC to allow for the separation of the incoming and outgoing beams. We show here how we can separate these beams using a Faraday rotator, thus eliminating the extinction ratio degradation which would result from misalignment of the cell.

The double-pass PC system is shown schematically in Fig. 6. The Faraday rotator and polarizers P1 and P2 (shared with the PC) define the input polarization for the PC. After an initial pass through the PC, the laser beam is reflected straight back by mirror M1 for the second pass, after which it gets separated from the input beam by the Faraday rotator. The only constraint other than the careful alignment of the direction and polarization of the input and output beams is the distance L of the mirror M1 from the PC. A typical PC temporal window is $T = 5–10 \text{ ns}$. As long as the total travel time of the pulse inside the system ($2L/c$, where $c$ is the speed of light) is shorter than $T$, the PC is active for both passes.

This system has not yet been implemented into a CPA laser chain, but initial tests on this configuration using a continuous-wave (CW) YAG laser at 1 $\mu$m have demonstrated the viability of the technique. A PC with a LiNbO$_3$ crystal was used, with high-quality Glan Laser polarizers. A picowattmeter detected the intensity of the CW beam. We measured an extinction ratio of $1.6 \times 10^5$ for the crossed polarizer without PC. When the PC was added, the extinction ratio decreased to $4 \times 10^3$ for a single pass. After double-passing the PC, the extinction ratio was measured to $2 \times 10^7$, 3 m away from the system’s output, which constitutes an improvement of 50 over the single-pass configuration. However, we found that the detected residual light signal was not the system’s leakage but in fact due to light back-scattered from the front side of the PC crystal. Indeed, the intensity of this scattered light varied as $1/d^2$, where $d$ is the distance between the front side of the PC and the detector. In a high power laser system, most this scattered light will be filtered away by the amplifiers. This should further improve the extinction ratio to a value between the measured $2 \times 10^5$ and the theoretical value of $(4 \times 10^3)^2 = 1.6 \times 10^7$ corresponding to a true double-pass into the PC system. The transmission through the system was 20%, but with better mirrors and all surfaces coated for antireflection, a transmission upwards of 50% can be expected.

B. Clean High-Energy Regenerative Amplifier Seed-Pulse Injection

While a double-pass PC may improve the prepulse situation in CPA lasers, it does little to increase the contrast in the temporal window of the PC or on the timescale of the stretched pulse (typically 0.2–1.0 ns). It is therefore highly desirable to find ways to improve the ASE contrast for short pulses. Techniques that have been devised to clean the pulses include temporal gating [62] and nonlinear discrimination [63], [51], but none of these eliminate the ASE at its source, during the amplification. The method we chose to reduce the ASE in our 10-Hz 100-fs Ti:sapphire laser chain is that of high-energy seed-pulse injection into the amplifier chain [22].

Fig. 7(a) shows a schematic of the typical CPA system. All the amplification—a factor of up to $10^{10}$ or more in the bigger chains—takes place essentially in one step, taking nanojoule pulses from the oscillator to multijoule energies. Along the way, the ASE present in the chain sees as much gain as the main pulse, or more if the laser is run into saturation. Therefore, considerable ASE background remain after compression.
for a low ICR. To reduce the gain seen by the ASE, we make use of a common practice of electronics: preamplification and filtering, as illustrated in Fig. 7(b). The low intensity ultrafast pulses are preamplified—without stretching—to the microjoule level. These pulses have an energy low enough to avoid damaging the preamplifier crystal but high enough to be cleaned when focused into a solid-state saturable absorber ["cleaner" in Fig. 7(b)]. The resulting high-contrast microjoule pulses are then sent into the usual CPA laser chain for the rest of the amplification. This method improves the contrast in two ways: 1) the pulses sent to the CPA chain are cleaner than those coming straight from the oscillator and 2) they need not go through as much amplification in the CPA system for a lower ASE buildup. High-energy seed-pulse injection has been used in the past, but only as applied to Nd:glass-based picosecond systems with nonstationary high-energy oscillators [64], [65]. Our technique is easily applicable to existing subpicosecond CPA laser systems with more conventional oscillators.

The original 10-Hz laser system with which we conducted the research discussed in Sections II and III is composed of: 1) a Clark-MXR self-mode-locked Ti:sapphire oscillator producing 3-nJ 50-fs pulses at 100 MHz with a spectral width of 20 nm centered at 780 nm; 2) an all reflective spherical-optics stretcher taking the pulses to 220-ps duration; 3) a saturated regenerative amplifier bringing the pulse energy up to 1 mJ; 4) two multipass amplifiers (2-pass and 4-pass) to further increase the energy to 250 mJ before compression; and 5) a grating compressor to bring the pulse duration back below 100 fs. Two Medox PC’s are used as single-pulse-selectors, one right after the oscillator to bring the repetition rate from 100 MHz to 10 Hz, and one after the regenerative amplifier to clean up the prepulses generated in the amplifier [66]. The preamplifier was placed between the first PC and the stretcher. It is a six-pass confocal Ti:sapphire amplifying stage with two concave mirrors and a flat mirror [67]. The crystal (0.15% doping, FOM 300) is pumped from both sides with a total of 10 mJ of green light to achieve a high gain without damage. The preamplified pulses have an energy of typically 3 μJ, and they are focused onto a solid-state saturable absorber (HOYA IR85) to remove the ASE present at this point in the chain. The clean microjoule pulses are then sent to the rest of the original 10-Hz chain.

The ICR of the ultrashort pulses was monitored at different stages of the amplification, for both the “original” and “improved” system, with a high-dynamic-range third-order autocorrelator [68], [22] with up to 1-ns range before and after the main pulse. Autocorrelations with ≈10^5 dynamic range were taken of the oscillator, of the preamplified pulse before and after the saturable absorber, and of the compressed pulse after the two-pass amplifier (10 mJ before compression, 4 mJ after). We first show autocorrelations of the oscillator (circles) and of the “original” amplified and compressed pulses (crosses) in Fig. 8. The sharp secondary peaks at 3 and 12 ps are artefacts due to surface reflections in the autocorrelator; negative delay times on the horizontal axis correspond to the front of the pulse. The temporal scale in Fig. 8(b) is logarithmic and concentrates on the front part of the pulse. The oscillator ICR is better than 10^7 on a temporal scale longer than 10 ps, and this is what the system starts with. After amplification in the “original” system, the contrast is now about 10^5 in the nanosecond timescale, in agreement with the plasma-shuttered streak camera measurement shown in Section III-A. The trace of the amplified pulse features shoulders in the first 10 ps; these are probably due to the uncompensated residual phase. Considering that the pulses are stretched to 220 ps during amplification, the contrast of 10^5 that extends to at least one nanosecond is not due to phase distortion but to the ASE. The third-order autocorrelations of the amplified pulse shows a FWHM duration of 300 fs, due to the material dispersion and the group velocity mismatch in the nonlinear crystals; single-shot autocorrelations of the pulses indicate an actual duration of ≈70 ps. The real ICR is, therefore, higher than that measured by the autocorrelation trace by a factor of about 5.

Fig. 9 shows the ICR measurement for the compressed pulses from the preamplifier without the saturable absorber (circles) and from the “improved” system, including cleaning and amplification up to 4 mJ (crosses). The preamplified pulse without cleaning has an ICR of ≈5 × 10^7 on the nanosecond scale, while the “improved” system has an ICR of 10^7. The microjoule pulses actually have a better contrast than shown in Fig. 9 upon injection through the system due to the
cleaning, which improved the ICR of the preamplified pulse. Because the ASE background is significantly suppressed by the saturable absorber, it was not measurable with the third-order autocorrelator. We can nevertheless estimate the ICR of the clean microjoule pulse from the transmission of the main pulse and the ASE measured with a fast photodiode: 0.5 and $4 \times 10^{-3}$, respectively. The contrast of the pulse right after the saturable absorber is then $5 \times 10^7/[4 \times 10^{-3}/0.5] \approx 6 \times 10^9$. Because these clean pulses were at the microjoule level, we were able to reduce the number of passes in the regenerative amplifier and limit the growth of the ASE background in the chain. This method could give even higher contrasts if the unstretched pulse could be amplified to higher energies ($>10 \mu J$) to take better advantage of the saturable absorber, but care must be taken to remain below the damage threshold of the preamplifier optics. With the present setup, injecting clean high-contrast microjoule pulses into the 10-Hz CPA laser chain has improved its ICR by at least a factor 100, from $10^5$ to $10^7$. This improvement came relatively cheaply (one low-energy multipass amplifier), with no loss in the final pulse energy and with minimal changes to the original laser system (a readjustment of the regenerative amplifier timing). Laser-matter interaction experiments conducted using this new and improved 10-Hz laser show very high plasma densities, and have allowed to study the atomic physics of strongly coupled plasmas in regimes that could not have been reached with the original low-contrast system [46], [47].

V. CONCLUSION

We have discussed and emphasized the importance of the laser ICR for ultrafast laser-solid interactions. We have shown the damaging effect that a poor contrast can have on three different basic and technological research projects using 100-fs laser pulses: the generation and probing of shocked solid matter, the acceleration of ions from solid targets and the development of jitter-free ultrafast detectors. We then introduced a novel pulse-contrast measurement technique, the high-dynamic-range plasma-shuttered streak camera, which extends the dynamic range of a picosecond visible streak camera from the usual 100 to a demonstrated $10^7$, with possible improvement to $10^9$. We measured the ICR of a 10-Hz 100-fs Ti:sapphire laser over the nanosecond range with this new diagnostics, and the obtained value of $10^5$ agrees with a third-order autocorrelation of the same system.

To improve this contrast for better solid-target interactions, we proposed and tested two new methods: the double-pass, high-contrast PC, and high-energy clean seed-pulse injection of the 10-Hz laser system. Initial demonstration experiments on the double-pass PC showed an improvement factor of 50 over the single-pass configuration, with an obvious possible extension up to a total double-pass extinction ratio of $1.6 \times 10^5$. On the 10-Hz laser, we have suppressed the ASE level by more than a factor of 100 by injecting high-energy seed-pulses into the existing system. The clean microjoule pulses were obtained with a simple six-pass preamplifier and a solid-state saturable absorber. Both techniques are relatively low-cost methods of improving the ICR of existing Ti:sapphire laser systems.

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